







DLP5533A-Q1 DLPS197A - SEPTEMBER 2020 - REVISED APRIL 2021

DLP5533A-Q1 0.55-Inch 1.3-Megapixel DMD for Automotive Exterior Lighting

1 Features

- Qualified for automotive applications
 - –40°C to 105°C operating DMD array temperature range
- The DLP5533A-Q1 automotive chipset includes:
 - DLP5533A-Q1 DMD
 - DLPC230-Q1 DMD controller
 - TPS99001-Q1 system management and illumination controller
- 0.55-inch diagonal micromirror array
 - 7.6-µm micromirror pitch
 - ±12° micromirror tilt angle (relative to flat state)
 - Bottom illumination for optimal efficiency and optical engine size
 - 1.3-megapixel array configured in 2:1 aspect ratio enabling high resolution and wide aspect ratio automotive applications
 - Compatible with LED or laser illumination
- 600-MHz sub-LVDS DMD interface for low power and emission
- 10-kHz DMD refresh rate over temperature
- Built-in self test of DMD memory cells

2 Applications

- High resolution headlight
- LIDAR optical filter

3 Description

The DLP5533A-Q1 automotive DMD, combined with the DLPC230-Q1 DMD controller and TPS99001-Q1 system management and illumination controller, provides the capability to achieve high performance high resolution headlight systems. The 2:1 aspect ratio supports very wide aspect ratio designs, and the 1.3-MP resolution enables high resolution symbol projection and adaptive driving beam applications. The DLP5533A-Q1 has more than 3 times the optical throughput of the preceding DLP3030-Q1 automotive DMD enabling an even larger field of view and higher lumens output. The DLP5533A-Q1 automotive DMD micromirror array is configured for bottom illumination which enables highly efficient and more compact optical engine designs. The S450 package has low thermal resistance to the DMD array to enable more efficient thermal solutions.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾ (2)	BODY SIZE (NOM)
DLP5533A-Q1	FYS (149)	22.30 mm × 32.20 mm

- For all available packages, see the orderable addendum at the end of the data sheet.
- This data sheet pertains to the specifications and application of this DMD in the headlight application. Please see the DLP5530A-Q1 data sheet (DLPS181) for head-up display specifications and application information.

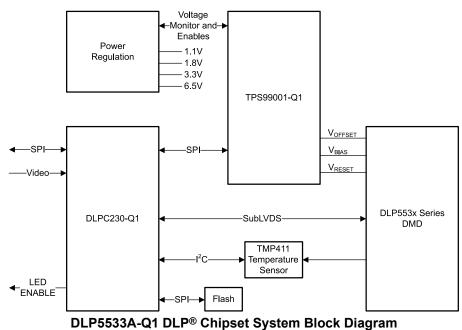




Table of Contents

1 Features1	7.2 Functional Block Diagram	18
2 Applications 1	7.3 Feature Description	
3 Description1	7.4 System Optical Considerations	20
4 Revision History2	7.5 DMD Image Performance Specification	22
5 Pin Configuration and Functions3	7.6 Micromirror Array Temperature Calculation	. 22
6 Specifications8	7.7 Micromirror Landed-On/Landed-Off Duty Cycle	. 2
6.1 Absolute Maximum Ratings8	8 Application and Implementation	26
6.2 Storage Conditions8	8.1 Application Information	. 26
6.3 ESD Ratings 8	8.2 Typical Application	. 20
6.4 Recommended Operating Conditions9	9 Power Supply Recommendations	30
Illumination Overfill Diagram9	9.1 Power Supply Power-Up Procedure	. 30
6.5 Thermal Information10	9.2 Power Supply Power-Down Procedure	30
6.6 Electrical Characteristics10	9.3 Power Supply Sequencing Requirements	. 3
6.7 Timing Requirements11	10 Layout	32
Electrical and Timing Diagrams11	10.1 Layout Guidelines	
6.8 Switching Characteristics14	11 Device and Documentation Support	
LPSDR and Test Load Circuit Diagrams14	11.1 Device Support	33
6.9 System Mounting Interface Loads15	11.2 Receiving Notification of Documentation Updates.	
System Interface Loads Diagram15	11.3 Support Resources	
6.10 Physical Characteristics of the Micromirror Array 15	11.4 Trademarks	
Array Physical Characteristics Diagram16	11.5 Electrostatic Discharge Caution	34
6.11 Micromirror Array Optical Characteristics 17	11.6 DMD Handling	
6.12 Window Characteristics17	11.7 Glossary	34
6.13 Chipset Component Usage Specification17	12 Mechanical, Packaging, and Orderable	
7 Detailed Description18	Information	34
7.1 Overview		

4 Revision History

CI	hanges from Revision * (September 2020) to Revision A (April 2021)	Page
•	Updated Current and Power Consumption in <i>Electrical Characteristics</i> section	

Submit Document Feedback

5 Pin Configuration and Functions

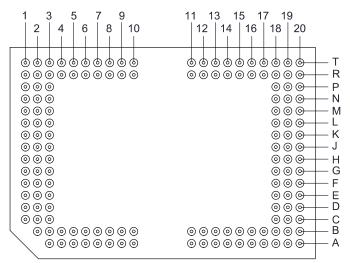


Figure 5-1. FYS Package 149-Pin CPGA Bottom View

Pin Functions - Connector Pins

PIN		TYPE	SIGNAL	DATA DATE	DESCRIPTION
NAME	NO.	ITPE	SIGNAL	DATA RATE	DESCRIPTION
DATA INPUTS	I .		1		
D_AN(0)	L2	I	SubLVDS	Double	Data, Negative
D_AN(1)	K2	I	SubLVDS	Double	Data, Negative
D_AN(2)	J2	ı	SubLVDS	Double	Data, Negative
D_AN(3)	H2	I	SubLVDS	Double	Data, Negative
D_AN(4)	F2	I	SubLVDS	Double	Data, Negative
D_AN(5)	E2	I	SubLVDS	Double	Data, Negative
D_AN(6)	D2	I	SubLVDS	Double	Data, Negative
D_AN(7)	C2	I	SubLVDS	Double	Data, Negative
D_AP(0)	L1	I	SubLVDS	Double	Data, Positive
D_AP(1)	K1	I	SubLVDS	Double	Data, Positive
D_AP(2)	J1	I	SubLVDS	Double	Data, Positive
D_AP(3)	H1	I	SubLVDS	Double	Data, Positive
D_AP(4)	F1	I	SubLVDS	Double	Data, Positive
D_AP(5)	E1	I	SubLVDS	Double	Data, Positive
D_AP(6)	D1	I	SubLVDS	Double	Data, Positive
D_AP(7)	C1	I	SubLVDS	Double	Data, Positive
D_BN(0)	K19	I	SubLVDS	Double	Data, Negative
D_BN(1)	J19	I	SubLVDS	Double	Data, Negative
D_BN(2)	H19	I	SubLVDS	Double	Data, Negative
D_BN(3)	G19	I	SubLVDS	Double	Data, Negative
D_BN(4)	E19	I	SubLVDS	Double	Data, Negative
D_BN(5)	D19	I	SubLVDS	Double	Data, Negative
D_BN(6)	C19	I	SubLVDS	Double	Data, Negative
D_BN(7)	B19	ı	SubLVDS	Double	Data, Negative



Pin Functions - Connector Pins (continued)

PIN		u		ector Pins (co				
NAME	NO.	TYPE	SIGNAL	DATA RATE	DESCRIPTION			
D_BP(0)	K20	I	SubLVDS	Double	Data, Positive			
D_BP(1)	J20	I	SubLVDS	Double	Data, Positive			
D_BP(2)	H20	I	SubLVDS	Double	Data, Positive			
D_BP(3)	G20	I	SubLVDS	Double	Data, Positive			
D_BP(4)	E20	I	SubLVDS	Double	Data, Positive			
D_BP(5)	D20	I	SubLVDS	Double	Data, Positive			
D_BP(6)	C20	I	SubLVDS	Double	Data, Positive			
D_BP(7)	B20	I	SubLVDS	Double	Data, Positive			
DCLK_AN	G2	ļ	SubLVDS	Double	Clock, Negative			
DCLK_AP	G1	ļ	SubLVDS	Double	Clock, Positive			
DCLK_BN	F19	ļ	SubLVDS	Double	Clock, Negative			
DCLK_BP	F20	ļ	SubLVDS	Double	Clock, Positive			
LS_CLKN	R3	I	SubLVDS	Single	Clock for Low Speed Interface, Negative			
LS_CLKP	Т3	I	SubLVDS	Single	Clock for Low Speed Interface, Positive			
LS_WDATAN	R2	I	SubLVDS	Single	Write Data for Low Speed Interface, Negative			
LS_WDATAP	T2	I	SubLVDS	Single	Write Data for Low Speed Interface, Positive			
CONTROL INPUTS								
DMD_DEN_ARSTZ	T10	I	LPSDR		Asynchronous Reset Active Low. Logic High Enables DMD.			
LS_RDATA_A	T5	0	LPSDR	Single	Enables DMD. Read Data for Low Speed Interface			
LS_RDATA_B	T6	0	LPSDR	Single	Read Data for Low Speed Interface			
TEMPERATURE SENSE	DIODE							
TEMP_N	P1	0			Calibrated temperature diode used to assist			
TEMP_P	N1	ļ			accurate temperature measurements of DMD die.			
RESERVED PINS								
VCCH	A8	Ground						
VCCH	A9	Ground						
VCCH	A10	Ground			Reserved Pin. Connect to Ground.			
VCCH	B8	Ground			Neserved Fin. Connect to Ground.			
VCCH	В9	Ground						
VCCH	B10	Ground						
VSSH	A11	Ground						
VSSH	A12	Ground						
VSSH	A13	Ground			Reserved Pin. Connect to Ground.			
VSSH	B11	Ground			Neserveu Fili. Collifect to Glouria.			
VSSH	B12	Ground						
VSSH	B13	Ground						

Pin Functions - Connector Pins (continued)

PIN				nector Pins (co				
NAME NO.		TYPE	SIGNAL	DATA RATE	DESCRIPTION			
POWER								
VBIAS	T7	Power			Supply voltage for positive bias level at			
VBIAS	T15	Power			micromirrors.			
VOFFSET	Т9	Power						
VOFFSET	T13	Power						
VOFFSET	A5	Power			Supply voltage for High Voltage CMOS core			
VOFFSET	B5	Power			logic. Supply voltage for offset level at micromirrors.			
VOFFSET	A16	Power						
VOFFSET	B16	Power			Supply voltage for negative reset level at micromirrors.			
VRESET	Т8	Power			Supply voltage for negative reset level at			
VRESET	T14	Power						
VDD	R4	Power						
VDD	R10	Power						
VDD	R11	Power						
VDD	R20	Power						
VDD	N2	Power						
VDD	M20	Power						
VDD	L3	Power			Supply voltage for Low Voltage CMOS core			
VDD	K18	Power			Supply voltage for Low Voltage CMOS core logic; for LPSDR inputs; for normal high level a micromirror address electrodes.			
VDD	H3	Power						
VDD	G18	Power						
VDD	E3	Power						
VDD	D18	Power						
VDD	C3	Power						
VDD	A6	Power						
VDD	A18	Power						
VDDI	T4	Power						
VDDI	R1	Power						
VDDI	M3	Power						
VDDI	L18	Power						
VDDI	J3	Power			Supply voltage for SubLVDS receivers.			
VDDI	H18	Power			Oupply voltage for OupLVDO receivers.			
VDDI	F3	Power						
VDDI	E18	Power						
VDDI	В3	Power						
VDDI	B18	Power						



Pin Functions - Connector Pins (continued)

NAME	PIN				lector Filis (co			
VSS T16 Ground VSS T19 Ground VSS T20 Ground VSS R5 Ground VSS R6 Ground VSS R7 Ground VSS R8 Ground VSS R9 Ground VSS R13 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P2 Ground VSS P20 Ground VSS N20 Ground VSS M2 Ground VSS M2 Ground VSS L19 Ground VSS L3 Ground VSS J18 Ground VSS J3 Ground VSS J3 Ground VSS D3 Ground	NAME	NO.	TYPE	SIGNAL	DATA RATE	DESCRIPTION		
VSS T19 Ground VSS T20 Ground VSS R5 Ground VSS R6 Ground VSS R7 Ground VSS R8 Ground VSS R13 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS J18 Ground VSS G3 Ground VSS G3 Ground VSS B2 Ground VSS B4 Ground	VSS	T1	Ground					
VSS T20 Ground VSS R6 Ground VSS R6 Ground VSS R7 Ground VSS R8 Ground VSS R9 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P2 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS N20 Ground VSS L19 Ground VSS L19 Ground VSS L3 Ground VSS J18 Ground VSS J3 Ground VSS G3 Ground VSS J3 Ground VSS B2 Ground VSS B2 Ground	VSS	T16	Ground					
VSS R6 Ground VSS R7 Ground VSS R7 Ground VSS R8 Ground VSS R8 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P2 Ground VSS P2 Ground VSS N19 Ground VSS N19 Ground VSS M1 Ground VSS M2 Ground VSS M2 Ground VSS L19 Ground VSS J18 Ground VSS J18 Ground VSS G3 Ground VSS D3 Ground VSS D3 Ground VSS B4 Ground VSS B4 Ground <td< td=""><td>VSS</td><td>T19</td><td>Ground</td><td></td><td></td><td></td></td<>	VSS	T19	Ground					
VSS R6 Ground VSS R7 Ground VSS R8 Ground VSS R8 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N20 Ground VSS M19 Ground VSS M2 Ground VSS M2 Ground VSS L19 Ground VSS L3 Ground VSS J18 Ground VSS J18 Ground VSS J18 Ground VSS F18 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground	VSS	T20	Ground					
VSS R7 Ground VSS R8 Ground VSS R9 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS J18 Ground VSS J18 Ground VSS G3 Ground VSS D3 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground	VSS	R5	Ground					
VSS R8 Ground VSS R9 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS M20 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS L20 Ground VSS L3 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground	VSS	R6	Ground					
VSS R9 Ground VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS J18 Ground VSS F18 Ground VSS D3 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B15 Ground VSS A3 Ground	VSS	R7	Ground					
VSS R13 Ground VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS L3 Ground VSS J18 Ground VSS J18 Ground VSS J3 Ground VSS J3 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground	VSS	R8	Ground					
VSS R14 Ground VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS L20 Ground VSS J18 Ground VSS J18 Ground VSS G3 Ground VSS J3 Ground VSS D3 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground VSS A4 Ground	VSS	R9	Ground					
VSS R15 Ground VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS G3 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground	VSS	R13	Ground					
VSS P2 Ground VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N19 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS D3 Ground VSS D3 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A7 Ground VSS A15 Ground <td< td=""><td>VSS</td><td>R14</td><td>Ground</td><td></td><td></td><td></td></td<>	VSS	R14	Ground					
VSS P3 Ground VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS L3 Ground VSS J18 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground VSS A4 Ground VSS A7 Ground VSS A7 Ground VSS A15 Ground <	VSS	R15	Ground					
VSS P20 Ground VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	P2	Ground					
VSS N19 Ground VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	P3	Ground					
VSS N20 Ground VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS D3 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A15 Ground VSS A15 Ground VSS A19 Ground	VSS	P20	Ground					
VSS M1 Ground VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	N19	Ground					
VSS M2 Ground VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	N20	Ground					
VSS L19 Ground Common return. Ground for all power. VSS L20 Ground Ground VSS K3 Ground Ground VSS J18 Ground Ground VSS G3 Ground Ground VSS D3 Ground Ground VSS B2 Ground Ground VSS B4 Ground Ground VSS B15 Ground Ground VSS A3 Ground Ground VSS A4 Ground Ground VSS A15 Ground Ground VSS A17 Ground Ground	VSS	M1	Ground					
VSS L19 Ground VSS L20 Ground VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	M2	Ground					
VSS K3 Ground VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	L19	Ground			Common return. Ground for all power.		
VSS J18 Ground VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	L20	Ground					
VSS G3 Ground VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	K3	Ground					
VSS F18 Ground VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	J18	Ground					
VSS D3 Ground VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	G3	Ground					
VSS C18 Ground VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	F18	Ground					
VSS B2 Ground VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	D3	Ground					
VSS B4 Ground VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	C18	Ground					
VSS B15 Ground VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	B2	Ground					
VSS B17 Ground VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	B4	Ground					
VSS A3 Ground VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	B15	Ground					
VSS A4 Ground VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	B17	Ground					
VSS A7 Ground VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	A3	Ground					
VSS A15 Ground VSS A17 Ground VSS A19 Ground	VSS	A4	Ground					
VSS A17 Ground VSS A19 Ground	VSS	A7	Ground					
VSS A19 Ground	VSS	A15	Ground					
	VSS	A17	Ground					
VSS A20 Cround	VSS	A19	Ground					
voo AZU Ground	VSS	A20	Ground					



Pin Functions - Test Pads

	ctions - restraus
NUMBER	SYSTEM BOARD
T11	Do not connect
T12	Do not connect
T17	Do not connect
T18	Do not connect
R12	Do not connect
R16	Do not connect
R17	Do not connect
R18	Do not connect
R19	Do not connect
P18	Do not connect
P19	Do not connect
N3	Do not connect
N18	Do not connect
M18	Do not connect
M19	Do not connect
B6	Do not connect
B7	Do not connect
B14	Do not connect
A14	Do not connect



6 Specifications

6.1 Absolute Maximum Ratings

see (1)

		MIN	NOM MAX	UNIT
SUPPLY VOLTAGE				
VDD	Supply voltage for LVCMOS core logic Supply voltage for LPSDR low speed interface	-0.5	2.3	V
VDDI	Supply voltage for SubLVDS receivers	-0.5	2.3	V
VOFFSET	Supply voltage for HVCMOS and micromirror electrode	-0.5	8.75	V
VBIAS	Supply voltage for micromirror electrode	-0.5	17	V
VRESET	Supply voltage for micromirror electrode	-11	0.5	V
VDDI–VDD	Supply voltage delta (absolute value)		0.3	V
VBIAS-VOFFSET	Supply voltage delta (absolute value)		8.75	V
VBIAS-VRESET	Supply voltage delta (absolute value)		28	V
INPUT VOLTAGE				
Input voltage for other inpu	its LPSDR	-0.5	VDD + 0.5	V
Input voltage for other inpu	its SubLVDS	-0.5	VDDI + 0.5	V
INPUT PINS	·			
V _{ID}	SubLVDS input differential voltage (absolute value)		810	mV
I _{ID}	SubLVDS input differential current		10	mA
TEMPERATURE DIODE				
I _{TEMP_DIODE}	Max current source into temperature diode		120	μA
ENVIRONMENTAL				
ILL _{OVERFILL}	Illumination overfill maximum heat load in area shown in Figure 6-1		37	mW/mm ²
T _{ARRAY}	Operating DMD array temperature	-40	105	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device is not implied at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure above or below the Recommended Operating Conditions for extended periods may affect device reliability.

6.2 Storage Conditions

Applicable for the DMD as a component or non-operating in a system.

		MIN	MAX	UNIT
T _{stg}	DMD storage temperature	-40	125	°C

6.3 ESD Ratings

				VALUE		UNIT
\/		Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾		±2000	V
V _{(ES}	SD)	Electrostatic discharge	Charged device model (CDM), per AEC Q	100-011	±750	V

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

Submit Document Feedback

6.4 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)(1)

		MIN	NOM	MAX	UNIT
SUPPLY VOLTAGE RA	ANGE				
VDD	Supply voltage for LVCMOS core logic Supply voltage for LPSDR low-speed interface	1.7	1.8	1.95	V
VDDI	Supply voltage for SubLVDS receivers	1.7	1.8	1.95	V
VOFFSET	Supply voltage for HVCMOS and micromirror electrode	8.25	8.5	8.75	V
VBIAS	Supply voltage for mirror electrode	15.5	16	16.5	V
VRESET	Supply voltage for micromirror electrode	-9.5	-10	-10.5	V
VDDI–VDD	Supply voltage delta (absolute value)			0.3	V
VBIAS-VOFFSET	Supply voltage delta (absolute value)			8.75	V
CLOCK FREQUENCY					
$f_{\sf max}$	Clock frequency for low speed interface LS_CLK			120	MHz
$f_{\sf max}$	Clock frequency for high speed interface DCLK			600	MHz
	Duty cycle distortion DCLK	44%		56%	
SUBLVDS INTERFACE	<u> </u>				
V _{ID}	SubLVDS input differential voltage (absolute value) ⁽²⁾	150	250	350	mV
V _{CM}	Common mode voltage (2)	700	900	1100	mV
Z _{LINE}	Line differential impedance (PWB/trace)	90	100	110	Ω
Z _{IN}	Internal differential termination resistance ⁽³⁾	80	100	120	Ω
ENVIRONMENTAL					
T _{ARRAY}	Operating DMD array temperature ⁽⁵⁾	-40		105	°C
ILL _{UV}	Illumination, wavelength < 395 nm ⁽⁴⁾			2	mW/cm ²
ILL _{OVERFILL}	Illumination overfill maximum heat load in area shown in Figure 6-1			28	mW/mm

- (1) Recommended Operating Conditions are applicable after the DMD is installed in the final product.
- (2) See Figure 6-6 and Figure 6-7
- (3) See Figure 6-8
- (4) The maximum operation conditions for operating temperature and UV illumination shall not be implemented simultaneously.
- (5) Operating profile information for device micromirror landed duty-cycle and temperature may be provided if requested.

Illumination Overfill Diagram

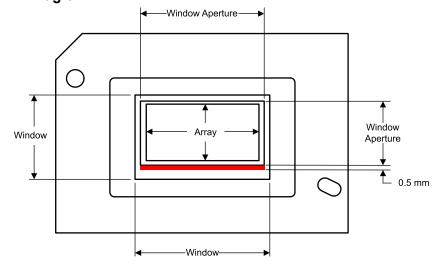


Figure 6-1. Illumination Overfill Diagram



6.5 Thermal Information

	FYS (CPGA)	UNIT				
	149 PINS					
Thermal resistance	Active area-to-test point 1 (TP1) (1) (2)	1.3	°C/W			
Thermal resistance	Active area-to-temperature sense diode ⁽¹⁾ (2)	0.8	°C/W			

- (1) The DMD is designed to conduct absorbed and dissipated heat to the back of the package. The cooling system must be capable of maintaining the package within the temperature range specified in the Section 6.4. The total heat load on the DMD is largely driven by the incident light absorbed by the active area, although other contributions include light energy absorbed by the window aperture and electrical power dissipation of the array. Optical systems should be designed to minimize the light energy falling outside the window clear aperture since any additional thermal load in this area can significantly degrade the reliability of the device.
- (2) The thermal resistance values provided here assumes a non-uniform illumination profile. Refer to Section 7.6 for details.

6.6 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted) (1)

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
CURRENT				-	
I _{DD}	Supply current: VDD ⁽²⁾	VDD = 1.95 V		310	mA
I _{DDI}	Supply current: VDDI ⁽²⁾	VDDI = 1.95 V		55	mA
I _{OFFSET}	Supply current: VOFFSET	VOFFSET = 8.75 V		6	mA
I _{BIAS}	Supply current: VBIAS	VBIAS = 16.5 V		1	mA
I _{RESET}	Supply current: VRESET	VRESET = -10.5 V		-4.5	mA
POWER					
P _{DD}	Supply power dissipation: VDD ⁽²⁾	VDD = 1.95 V		604.5	mW
P _{DDI}	Supply power dissipation: VDDI ⁽²⁾	VDDI = 1.95 V		107.25	mW
P _{OFFSET}	Supply power dissipation: VOFFSET	VOFFSET = 8.75 V		52.5	mW
P _{BIAS}	Supply power dissipation: VBIAS	VBIAS = 16.5 V		16.5	mW
P _{RESET}	Supply power dissipation: VRESET	VRESET = -10.5 V		47.25	mW
P _{TOTAL}	Supply power dissipation: Total			828	mW
LPSDR INPU	UT ⁽³⁾				
V _{IH(DC)}	DC input high voltage		0.7 × VDD	VDD + 0.3	V
V _{IL(DC)}	DC input low voltage		-0.3	0.3 × VDD	V
V _{IH(AC)}	AC input high voltage		0.8 × VDD	VDD + 0.3	V
V _{IL(AC)}	AC input low voltage		-0.3	0.2 × VDD	V
ΔV_{T}	Hysteresis (V _{T+} – V _T)	See Figure 6-9	0.1 × VDD	0.4 × VDD	V
I _{IL}	Low-level input current	VDD = 1.95 V; V _I = 0 V	-100		nA
I _{IH}	High-level input current	VDD = 1.95 V; V _I = 1.95 V		300	nA
LPSDR OUT	PUT (4)				
V _{OH}	DC output high voltage	I _{OH} = -2mA	0.8 × VDD		V
V _{OL}	DC output low voltage	I _{OL} = 2mA		0.2 × VDD	V
CAPACITAN	ICE				
<u> </u>	Input capacitance LPSDR	f = 1 MHz		10	pF
C _{IN}	Input capacitance SubLVDS	f = 1 MHz		20	þг
C _{OUT}	Output capacitance	f = 1 MHz		10	pF
C _{RESET}	Reset group capacitance	f = 1 MHz (1152 X 144 micromirrors)	350	400 450	pF
СтемР	Temperature sense diode capacitance	f = 1 MHz		20	pF

- (1) Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted.
- (2) Supply power dissipation based on non-compressed commands and data.
- (3) LPSDR input specifications are for pin DMD_DEN_ARSTZ.
- (4) LPSDR output specification is for pins LS_RDATA_A and LS_RDATA_B.

Submit Document Feedback



6.7 Timing Requirements

Device electrical characteristics are over Recommended Operating Conditions unless otherwise noted

			MIN	NOM MA	X UNIT
LPSDR					
t _r	Rise slew rate (1)	(20% to 80%) × VDD	0.25		V/ns
t _f	Fall slew rate (1)	(80% to 20%) × VDD	0.25		V/ns
t _{W(H)}	Pulse duration LS_CLK high ⁽³⁾	50% to 50% reference points	0.75		ns
t _{W(L)}	Pulse duration LS_CLK low ⁽³⁾	50% to 50% reference points	0.75		ns
t _{su}	Setup time ⁽³⁾	LS_WDATA valid before LS_CLK ↑ or LS_CLK ↓	1.5		ns
t _h	Hold time ⁽³⁾	LS_WDATA valid after LS_CLK ↑ or LS_CLK ↓	1.5		ns
SubLVDS	1		-		
t _r	Rise slew rate ⁽²⁾	20% to 80% reference points	0.7	1	V/ns
t _f	Fall slew rate ⁽²⁾	80% to 20% reference points	0.7	1	V/ns
t _c	Cycle time DCLK ⁽³⁾		1.61	1.67	ns
t _{W(H)}	Pulse duration DCLK high ⁽³⁾	50% to 50% reference points	0.75		ns
t _{W(L)}	Pulse duration DCLK low(3)	50% to 50% reference points	0.75		ns
t _{WINDOW}	Window time ^{(3) (4)}	Setup time + Hold time	0.3		ns
t _{LVDS-ENABLE+REFGEN}	Power-up receiver ⁽⁵⁾			200	0 ns

- (1) Specification is for DMD_DEN_ARSTZ pin. Refer to LPSDR input rise and fall slew rate in Figure 6-2
- (2) See Figure 6-3
- (3) See Figure 6-4
- (4) See Figure 6-5
- (5) Specification is for SubLVDS receiver time only and does not take into account commanding and latency after commanding.

Electrical and Timing Diagrams

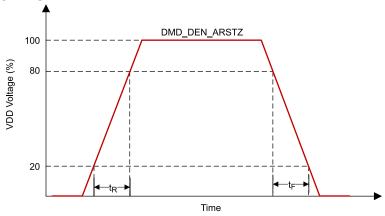


Figure 6-2. LPSDR Input Rise and Fall Slew Rate



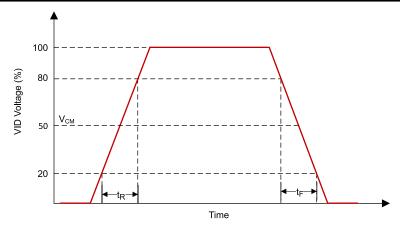


Figure 6-3. SubLVDS Input Rise and Fall Slew Rate

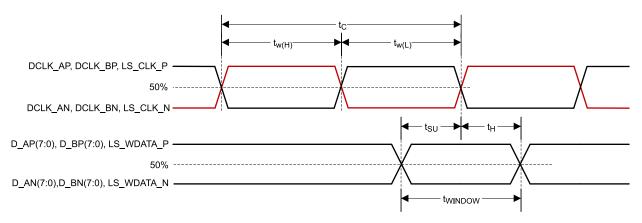
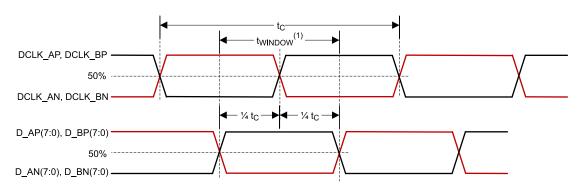


Figure 6-4. SubLVDS Switching Parameters



(1) High-speed training scan window

Figure 6-5. High-Speed Training Scan Window

Submit Document Feedback

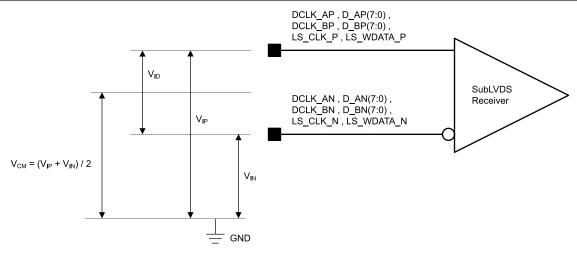


Figure 6-6. SubLVDS Voltage Parameters

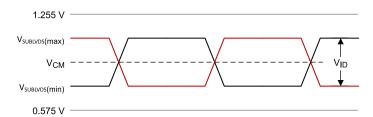


Figure 6-7. SubLVDS Waveform Parameters

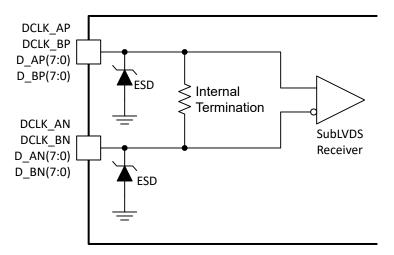


Figure 6-8. SubLVDS Equivalent Input Circuit



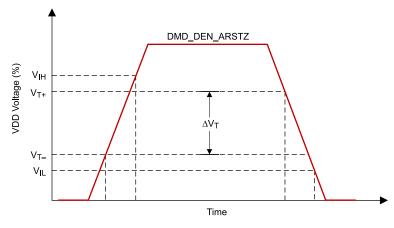


Figure 6-9. LPSDR Input Hysteresis

6.8 Switching Characteristics

Over operating free-air temperature range (unless otherwise noted)(1)

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
t _{PD}	Output propagation, clock to Q, rising edge of LS_CLK (differential clock signal) input to LS_RDATA output. ⁽²⁾	C _L = 45 pF		15	ns
	Slew rate, LS_RDATA		0.5		V/ns
	Output duty cycle distortion, LS_RDATA_A and LS_RDATA_B		40%	60%	

- (1) Device electrical characteristics are over Recommended Operating Conditions unless otherwise noted.
- (2) See Figure 6-10 and Figure 6-11

LPSDR and Test Load Circuit Diagrams

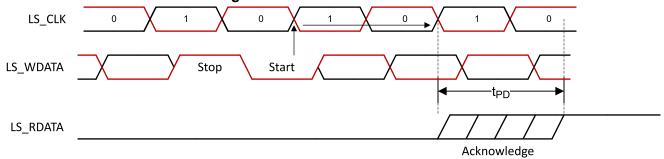


Figure 6-10. LPSDR Read Out

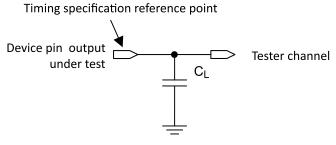


Figure 6-11. Test Load Circuit for Output Propagation Measurement

Submit Document Feedback

6.9 System Mounting Interface Loads

PARAMETER	MIN	NOM	MAX	UNIT
Condition 1: Maximum load evenly distributed within each area (1)				
Thermal Interface Area			110.8	N
Electrical Interface Area			111.3	IN
Condition 2: Maximum load evenly distributed within each area (1)				
Thermal Interface Area			0	N
Electrical Interface Area			222.1	IN

(1) See Figure 6-12

System Interface Loads Diagram

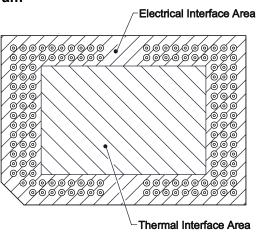


Figure 6-12. System Interface Loads

6.10 Physical Characteristics of the Micromirror Array

	PARAMETER	VALUE	UNIT	
М	Number of active columns ⁽¹⁾		1152	micromirrors
N	Number of active rows ⁽¹⁾		1152	micromirrors
ε	Micromirror (pixel) pitch - diagonal ⁽¹⁾		7.6	μm
Р	Micromirror (pixel) pitch - horizontal and vertical ⁽¹⁾		10.8	μm
	Micromirror active array width	(P × M) + (P / 2)	12.447	mm
	Micromirror active array height	(P x N) / 2 + (P / 2)	6.226	mm
	Micromirror active border	Pond of micromirrors (POM) (2)	10	micromirrors/side

⁽¹⁾ See Figure 6-13

⁽²⁾ The structure and qualities of the border around the active array includes a band of partially functional micromirrors called the POM. These micromirrors are structurally and/or electrically prevented from tilting toward the bright or ON state, but still require an electrical bias to tilt toward OFF.



Array Physical Characteristics Diagram

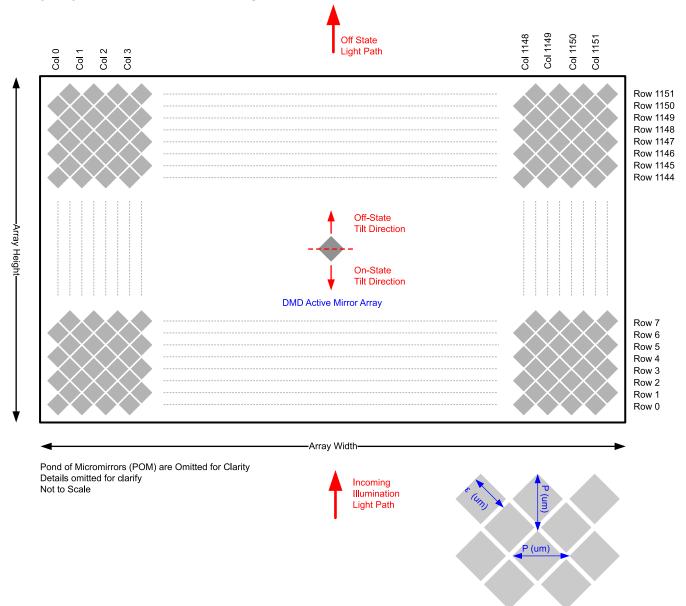


Figure 6-13. Micromirror Array Physical Characteristics



6.11 Micromirror Array Optical Characteristics

PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT
Micromirror tilt angle	DMD landed state ⁽¹⁾		12		degree
Micromirror tilt angle tolerance ⁽²⁾		-1		1	degree
DMD efficiency ⁽³⁾	420 nm - 700 nm		66%		

- (1) Measured relative to the plane formed by the overall micromirror array at 25°C.
- (2) For some applications, it is critical to account for the micromirror tilt angle variation in the overall optical system design. With some optical system designs, the micromirror tilt angle variation within a device may result in perceivable non-uniformities in the light field reflected from the micromirror array. With some optical system designs, the micromirror tilt angle variation between devices may result in colorimetry variations, system efficiency variations, or system contrast variations.
- (3) DMD efficiency is measured photopically under the following conditions: 24° illumination angle, F/2.4 illumination and collection apertures, uniform source spectrum (halogen), uniform pupil illumination, the optical system is telecentric at the DMD, and the efficiency numbers are measured with 100% electronic micromirror landed duty-cycle and do not include system optical efficiency or overfill loss. This number is measured under conditions described above and deviations from these specified conditions could result in a different efficiency value in a different optical system. The factors that can influence the DMD efficiency related to system application include: light source spectral distribution and diffraction efficiency at those wavelengths (especially with discrete light sources such as LEDs or lasers), and illumination and collection apertures (F/#) and diffraction efficiency. The interaction of these system factors as well as the DMD efficiency factors that are not system dependent are described in DLPA083A

6.12 Window Characteristics

F	PARAMETER	MIN	NOM	MAX	UNIT
Window material designation			Corning Eagle XG		
Window refractive index	at wavelength 546.1 nm		1.5119		
Window aperture (1)				See (1)	

(1) See the mechanical package ICD for details regarding the size and location of the window aperture.

6.13 Chipset Component Usage Specification

The DLP5533A-Q1 is a component of a chipset. Reliable function and operation of the DLP5533A-Q1 requires that it be used in conjunction with the TPS99001-Q1 and DLPC230-Q1, and includes components that contain or implement TI DMD control technology. TI DMD control technology consists of the TI technology and devices used for operating or controlling a DLP DMD.

Note

TI assumes no responsibility for image quality artifacts or DMD failures caused by optical system operating conditions exceeding limits described previously.



7 Detailed Description

7.1 Overview

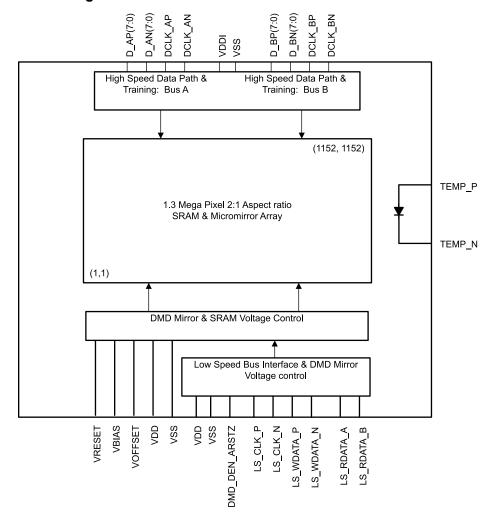
The DLP5533A-Q1 Automotive DMD consists of 1,327,104 highly reflective, digitally switchable, micrometer-sized mirrors organized in a two-dimensional array. As shown in Figure 6-13, the micromirror array consists of 1152 micromirror columns × 1152 micromirror rows in a diamond pixel configuration with a 2:1 aspect ratio.

Around the perimeter of the 1152×1152 array of micromirrors is a uniform band of border micromirrors called the Pond of Micromirrors (POM). The border micromirrors are not user-addressable. The border micromirrors land in the -12° position once power has been applied to the device. There are 10 border micromirrors on each side of the 1152×1152 active array.

Due to the diamond pixel configuration, the columns of each odd row are offset by half a pixel from the columns of the even row. Each mirror is switchable between two discrete angular positions: –12° and +12°. The mirrors are illuminated from the bottom which allows for compact and efficient system optical design.

Although the native resolution of the DLP5533A-Q1 is 1152 × 1152, when paired with the DLPC230-Q1 controller, the DLP5533A-Q1 can be driven with different resolutions to utilize the 2:1 aspect ratio. For example, Headlight applications typically use a resolution of 1152 × 576. Please see the DLPC230-Q1 automotive DMD controller data sheet (DLPS054) for a list of supported resolutions.

7.2 Functional Block Diagram



Submit Document Feedback

7.3 Feature Description

The DLP5533A-Q1 consists of a two-dimensional array of 1-bit CMOS memory cells driven by a sub-LVDS bus from the DLPC230-Q1 and powered by the TPS99001-Q1. The temperature sensing diode is used to continuously monitor the DMD array temperature.

To ensure reliable operation the DLP5533A-Q1 must be used with the DLPC230-Q1 DMD display controller and the TPS99001-Q1 system management and illumination controller.

7.3.1 Sub-LVDS Data Interface

The Sub-LVDS signaling protocol was designed to enable very fast DMD data refresh rates while simultaneously maintaining low power and low emission.

Data is loaded into the SRAM under each micromirror using the sub-LVDS interface from the DLPC230-Q1. This interface consists of 16 pairs of differential data signals plus two clock pairs into two separate buses A and B loading the left and right half of the SRAM array. The data is latched on both transitions creating a double data rate (DDR) interface. The sub-LVDS interface also implements a continuous training algorithm to optimize the data and clock timing to allow for a more robust interface.

The entire DMD array of 1.3 million pixels can be updated at a rate of less than 100 μ s as a result of the high speed sub-LVDS interface.

7.3.2 Low Speed Interface for Control

The purpose of the low speed interface is to configure the DMD at power up and power down and to control the micromirror reset voltage levels that are synchronized with the data loading. The micromirror reset voltage controls the time when the mirrors are mechanically switched. The low speed differential interface includes 2 pairs of signals for write data and clock, and 2 single-ended signals for output (A and B).

7.3.3 DMD Voltage Supplies

The micromirrors require unique voltage levels to control the mechanical switching from -12° to +12°. These voltage levels are nominally 16 V, 8.5 V, and -10 V (VBIAS, VOFFSET, and VRESET), and are generated by the TPS99001-Q1.

7.3.4 Asynchronous Reset

Reset of the DMD is required and controlled by the DLPC230-Q1 via the signal DMD_DEN_ARSTZ.

7.3.5 Temperature Sensing Diode

The DMD includes a temperature sensing diode designed to be used with the TMP411 temperature monitoring device. The DLPC230-Q1 monitors the temperature sense diode via the TMP411. The DLPC230-Q1 operation of the DMD timing can be adjusted based on the DMD array temperature, therefore this connection is essential to ensure reliable operation of the DMD.

Figure 7-1 shows the typical connection between the DLPC230-Q1, TMP411, and the DMD.

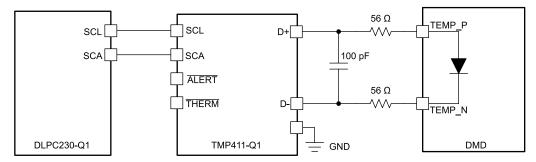


Figure 7-1. Temperature Sense Diode Typical Circuit Configuration



7.3.5.1 Temperature Sense Diode Theory

A temperature sensing diode is based on the fundamental current and temperature characteristics of a transistor. The diode is formed by connecting the transistor base to the collector. Three different known currents flow through the diode and the resulting diode voltage is measured in each case. The difference in their base–emitter voltages is proportional to the absolute temperature of the transistor.

Refer to the TMP411-Q1 data sheet for detailed information about temperature diode theory and measurement. Figure 7-2 and Figure 7-3 illustrate the relationships between the current and voltage through the diode.

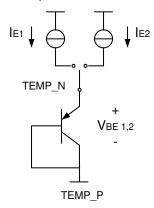


Figure 7-2. Temperature Measurement Theory

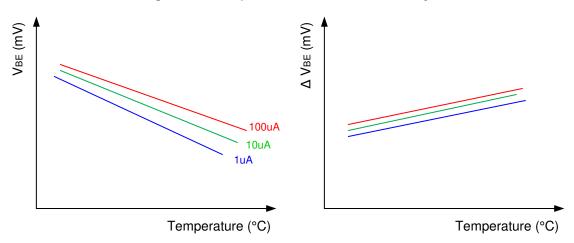


Figure 7-3. Example of Delta VBE Versus Temperature

7.4 System Optical Considerations

Optimizing system optical performance and image performance strongly relates to optical system design parameter trades. Although it is not possible to anticipate every conceivable application, projector image and optical performance is contingent on compliance to the optical system operating conditions described in the following sections.

7.4.1 Numerical Aperture and Stray Light Control

The numerical aperture of the illumination and projection optics at the DMD optical area should be the same. This cone angle defined by the numerical aperture should not exceed the nominal device mirror tilt angle unless appropriate apertures are added in the illumination and/or projection pupils to block out flat-state and stray light from the projection lens. The mirror tilt angle defines the DMD's capability to separate the "On" optical path from any other light path, including undesirable flat-state specular reflections from the DMD window, DMD border structures, or other system surfaces near the DMD such as prism or lens surfaces.

Submit Document Feedback



7.4.2 Pupil Match

TI's optical and image performance specifications assume that the exit pupil of the illumination optics is nominally centered and located at the entrance pupil position of the projection optics. Misalignment of pupils between the illumination and projection optics can degrade screen image uniformity and cause objectionable artifacts in the display's border and/or active area. These artifacts may require additional system apertures to control, especially if the numerical aperture of the system exceeds the pixel tilt angle.

7.4.3 Illumination Overfill

Overfill light illuminating the area outside the active array can create artifacts from the mechanical features and other surfaces that surround the active array. These artifacts may be visible in the projected image. The illumination optical system should be designed to minimize light flux incident outside the active array and on the window aperture. Depending on the particular system's optical architecture and assembly tolerances, this amount of overfill light on the area outside of the active array may still cause artifacts to be visible.

Illumination light and overfill can also induce undesirable thermal conditions on the DMD, especially if illumination light impinges directly on the DMD window aperture or near the edge of the DMD window. Heat load on the aperture in the areas shown in Figure 6-1 should not exceed the values listed in *Recommended Operating Conditions*. This area is a 0.5-mm wide area the length of the aperture opening. The values listed in *Recommended Operating Conditions* assume a uniform distribution. For a non-uniform distribution please contact TI for additional information.

Note

TI ASSUMES NO RESPONSIBILITY FOR IMAGE QUALITY ARTIFACTS OR DMD FAILURES CAUSED BY OPTICAL SYSTEM OPERATING CONDITIONS EXCEEDING LIMITS DESCRIBED PREVIOUSLY.



7.5 DMD Image Performance Specification

Table 7-1. DMD Image Performance

PARAMETER ⁽¹⁾ (2)	MIN	NOM	MAX	UNIT
Dark Blemishes - Viewed on a linear blue 60 screen. (2)			6	
Light Blemishes - Viewed on a linear gray 10 screen.			6	
Bright Pixels - Viewed on a linear gray 10 screen. (3) (4)			6	micromirrors
Dark Pixels - Viewed on a white screen. ⁽⁴⁾			6	micromirrors

- (1) Blemish counts do not include reflections or shadows of the same artifact. Any artifact that is not specifically called out in this table is acceptable. Viewing distance must be > 60 in. Screen size should be similar to application image size. All values referenced are in linear gamma. Non-linear gamma curves may be running by default, and it should be ensured with a TI applications engineer that the equivalent linear gamma value as specified is used to judge artifacts.
- (2) Linear gray 5 may be substituted in monochrome applications.
- (3) Limitation: Only from (row 517, column 0) to (row 1151, column 1151), see Micromirror Array Physical Characteristics.
- (4) Minimum distance between non-operational single pixels is 20 mirrors.

7.6 Micromirror Array Temperature Calculation

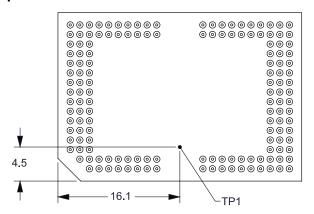


Figure 7-4. DMD Thermal Test Points

7.6.1 Temperature Rise Through the Package for Heatsink Design

When designing the DMD heatsink solution, the package thermal resistance from array to reference ceramic temperature (thermocouple location TP1 in Figure 7-4) can be used to determine the temperature rise through the package as given by the following equations:

$$T_{ARRAY-TO-CERAMIC} = Q_{ARRAY} \times R_{ARRAY-TO-CERAMIC}$$
(1)

$$Q_{\text{ILLUMINATION}} = (Q_{\text{INCIDENT}} \times \text{DMD Absorption Constant})$$
 (2)

$$Q_{ARRAY} = Q_{ELECTRICAL} + Q_{ILLUMINATION}$$
(3)

where

- T_{ARRAY-TO-CERAMIC} = temperature rise from array to thermal test point TP1 (°C/W)
- T_{CERAMIC} = measured ceramic temperature, at the TP1 location in Figure 7-4 (°C)
- R_{ARRAY-TO-CERAMIC} = DMD package thermal resistance from array to thermal test point TP1 (°C/W), see Section 6.5
- Q_{ARRAY} = total power, electrical plus absorbed, on the DMD array (W)
- Q_{ELECTRICAL} = nominal electrical power dissipation by the DMD (W)
- Q_{ILLUMINATION} = absorbed illumination heat load (W)
- Q_{INCIDENT} = incident power on the DMD (W)

The DMD package thermal resistance from array to ceramic ($R_{ARRAY-TO-CERAMIC}$) assumes a non-uniform illumination distribution on the DMD as shown in Figure 7-5. For illumination profiles more uniform than the one highlighted in Figure 7-5, the value provided here is valid. However, for more non-uniform profiles (e.g.

Gaussian distribution) the thermal resistance will be higher. Please contact TI to determine an accurate value for this case.

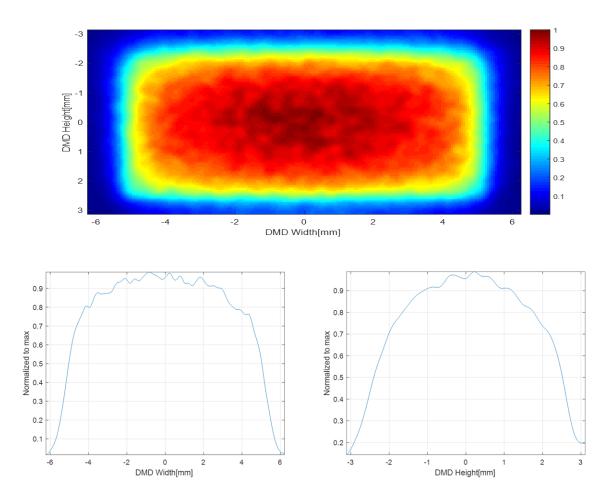


Figure 7-5. Non-Uniform Illumination Profile

The DMD absorption constant is a function of illumination distribution on the active array and the array border, angle of incidence (AOI), f number of the system, and operating state of the mirrors. The absorption constant is higher in the OFF state than in the ON state. Equations to calculate the absorption constant are provided for both ON and OFF mirror states. They assume an AOI of 34 degrees, an f/1.7 system, and they account for the distribution of light on the active array, POM, and array border.

DMD Absorption Constant (OFF state) =
$$0.895 - 0.004783 \times (\% \text{ of light on ActiveArray} + POM)$$
 (4)

Electrical power dissipation of the DMD is variable and depends on the voltages, data rates, and operating frequencies.



The following sample calculations assume 10% of the total incident light falls outside of the active array and POM, and the mirrors are in the OFF state.

- 1. DMD Absorption Constant = $0.895 0.004783 \times 90 = 0.46$
- 2. Q_{ELECTRICAL} = 0.4 W
- 3. $R_{ARRAY-TO-CERAMIC} = 1.3$ °C/W
- 4. Q_{INCIDENT} = 10 W
- 5. $Q_{ARRAY} = 0.4 W + (0.46 \times 10 W) = 5 W$
- 6. $T_{ARRAY-TO-CERAMIC} = 5 \text{ W} \times 1.3^{\circ}\text{C/W} = 6.5^{\circ}\text{C}$

7.6.2 Monitoring Array Temperature Using the Temperature Sense Diode

The active array temperature can be computed analytically from the temperature sense diode measurement, the thermal resistance from array to diode, the electrical power, and the illumination heat load. The relationship between array temperature and the temperature sense diode is provided by the following equations:

$$T_{ARRAY} = T_{DIODE} + Q_{ARRAY} \times R_{ARRAY-TO-DIODE}$$
(6)

$$Q_{\text{ILLUMINATION}} = (Q_{\text{INCIDENT}} \times \text{DMD Absorption Constant})$$
 (7)

$$Q_{ARRAY} = Q_{ELECTRICAL} + Q_{ILLUMINATION}$$
(8)

where

- T_{ARRAY} = computed array temperature (°C)
- T_{DIODE} = measured temperature sense diode temperature (°C)
- R_{ARRAY-TO-DIODE} = package thermal resistance from array to diode (°C/W)
- Q_{ARRAY} = total power, electrical plus absorbed, on the DMD array (W) Refer to Section 7.6.1 for details
- Q_{ELECTRICAL} = nominal electrical power dissipation by the DMD (W)
- Q_{ILLUMINATION} = absorbed illumination heat load (W)
- Q_{INCIDENT} = incident power on the DMD (W)

The temperature sense diode to array thermal resistance (R_{ARRAY-TO-DIODE}) assumes a non-uniform illumination distribution on the DMD as shown in Figure 7-5. For illumination profiles more uniform than the one highlighted in Figure 7-5, the value provided here is valid. However, for more non-uniform profiles (e.g. Gaussian distribution), the thermal resistance will be higher. Please contact TI to determine an accurate value for this case.

The following sample calculations assume 10% of the total incident light falls outside of the active array and POM, and the mirrors are in the OFF state.

- 1. DMD Absorption Constant = $0.895 0.004783 \times 90 = 0.46$
- 2. QFI FCTRICAL = 0.4 W
- 3. $R_{ARRAY-TO-DIODE} = 0.8$ °C/W
- 4. Q_{INCIDENT} = 10 W
- 5. $T_{DIODE} = 50$ °C
- 6. $Q_{ARRAY} = 0.4 W + (0.46 \times 10 W) = 5 W$
- 7. $T_{ARRAY} = 50^{\circ}C + (5 \text{ W} \times 0.8^{\circ}C/\text{W}) = 54.0^{\circ}C$

Submit Document Feedback

7.7 Micromirror Landed-On/Landed-Off Duty Cycle

7.7.1 Definition of Micromirror Landed-On/Landed-Off Duty Cycle

The micromirror landed-on/landed-off duty cycle (landed duty cycle) denotes the amount of time (as a percentage) that an individual micromirror is landed in the ON state versus the amount of time the same micromirror is landed in the OFF state.

As an example, a landed duty cycle of 90/10 indicates that the referenced pixel is in the ON state 90% of the time (and in the OFF state 10% of the time), whereas 10/90 would indicate that the pixel is in the OFF state 90% of the time. Likewise, 50/50 indicates that the pixel is ON 50% of the time and OFF 50% of the time.

Note that when assessing landed duty cycle, the time spent switching from one state (ON or OFF) to the other state (OFF or ON) is considered negligible and is thus ignored.

Since a micromirror can only be landed in one state or the other (ON or OFF), the two numbers (percentages) always add to 100.



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The DLP5533A-Q1 chipset is designed to support projection-based automotive applications such as high resolution adaptive driving beam (ADB) headlights.

8.2 Typical Application

The chipset consists of three components—the DLP5533A-Q1 automotive DMD, the DLPC230-Q1, and the TPS99001-Q1. The DMD is a light modulator consisting of tiny mirrors that are used to form and project images. The DLPC230-Q1 is a controller for the DMD; it formats incoming video and controls the timing of the DMD illumination sources and the DMD in order to display the incoming video. The TPS99001-Q1 is a high performance voltage regulator for the DMD and a management IC for the entire chipset. In conjunction, the DLPC230-Q1 and the TPS99001-Q1 can be used for system-level monitoring, diagnostics, and failure detection features. Figure 8-1 is a system level block diagram with these devices in the DLP headlight module configuration and displays the primary features and functions of each device.

Product Folder Links: DLP5533A-Q1

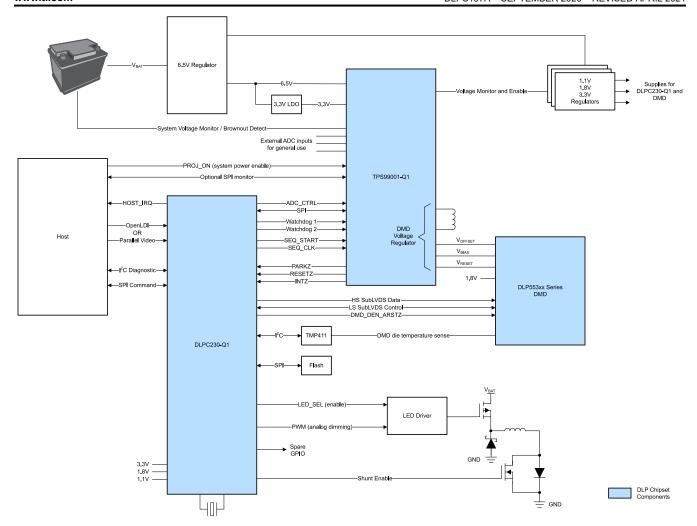


Figure 8-1. Headlight System Block Diagram



8.2.1 Application Overview

Figure 8-1 shows the system block diagram for a DLP headlight module. The system uses the DLPC230-Q1, TPS99001-Q1, and the DLP5533A-Q1 automotive DMD to enable a headlight projection system with unprecedented resolution and grayscale light control. The combination of the DLPC230-Q1 and TPS99001-Q1 removes the need for external SDRAM and a dedicated microprocessor. The chipset manages the illumination control of LED sources, power sequencing functions, and system management functions. Additionally, the chipset supports numerous system diagnostic and built-in self test (BIST) features. The following paragraphs describe the functionality of the chipset used for a headlight projection system in more detail.

The DLPC230-Q1 is a controller for the DMD and the light sources in the DLP headlight module. It receives input video from the host and synchronizes DMD and light source timing in order to achieve the desired video. The DLPC230-Q1 formats input video data that is displayed on the DMD. It synchronizes these video segments with light source timing in order to create a video with grayscale shading.

The DLPC230-Q1 receives inputs from a host processor in the vehicle. The host provides commands and input video data. Host commands can be sent using either the I²C bus or SPI bus. The bus that is not being used for host commands can be used as a read-only bus for diagnostic purposes. Input video can be sent over an OpenLDI bus or a parallel 24-bit bus. The 24-bit bus can be limited to only 8-bits of data for single light source systems such as headlights. The SPI flash memory provides the embedded software for the DLPC230-Q1's ARM core, any calibration data, and default settings. The TPS99001-Q1 provides diagnostic and monitoring information to the DLPC230-Q1 using an SPI bus and several other control signals such as PARKZ, INTZ, and RESETZ to manage power-up and power-down sequencing. The TMP411 uses an I²C interface to provide the DMD array temperature to the DLPC230-Q1.

The outputs of the DLPC230-Q1 are configuration and monitoring commands to the TPS99001-Q1, timing controls to the LED or laser driver, control and data signals to the DMD, and monitoring and diagnostics information to the host processor. The DLPC230-Q1 communicates with the TPS99001-Q1 over an SPI bus. It uses this to configure the TPS99001-Q1 and to read monitoring and diagnostics information from the TPS99001-Q1. The DLPC230-Q1 sends drive enable signals to the LED or laser driver, and synchronizes this with the DMD mirror timing. The control signals to the DMD are sent using a sub-LVDS interface.

The TPS99001-Q1 is a highly integrated mixed-signal IC that controls DMD power, the timing and amplitude of the LEDs or lasers, and provides monitoring and diagnostics information for the DLP headlight module. The power sequencing and monitoring blocks of the TPS99001-Q1 properly power up the DMD and provide accurate DMD voltage rails (–16 V, 8.5 V, and 10 V), and then monitor the system's power rails during operation. The integration of these functions into one IC significantly reduces design time and complexity. The TPS99001-Q1 also has several output signals that can be used to control a variety of LED or laser driver topologies. The TPS99001-Q1 has several general-purpose ADCs that designers can use for system level monitoring, such as over-brightness detection.

The TPS99001-Q1 receives inputs from the DLPC230-Q1, the power rails it monitors, the host processor, and potentially several other ADC ports. The DLPC230-Q1 sends configuration and control commands to the TPS99001-Q1 over an SPI bus and several other control signals. The DLPC230-Q1's clocks are also monitored by the watchdogs in the TPS99001-Q1 to detect any errors. The power rails are monitored by the TPS99001-Q1 in order to detect power failures or glitches and request a proper power down of the DMD in case of an error. The host processor can read diagnostics information from the TPS99001-Q1 using a dedicated SPI bus, which enables independent monitoring. Additionally the host can request the image to be turned on or off using a PROJ_ON signal. Lastly, the TPS99001-Q1 has several general-purpose ADCs that can be used to implement system level monitoring functions.

The outputs of the TPS99001-Q1 are diagnostic information and error alerts to the DLPC230-Q1, and control signals to the LED or laser driver. The TPS99001-Q1 can output diagnostic information to the host and the DLPC230-Q1 over two SPI buses. In case of critical system errors, such as power loss, it outputs signals to the DLPC230-Q1 that trigger power down or reset sequences. It also has output signals that can be used to implement various LED or laser driver topologies.

The DMD is a micro-electro-mechanical system (MEMS) device that receives electrical signals as an input (video data), and produces a mechanical output (mirror position). The electrical interface to the DMD is a sub-LVDS

Product Folder Links: DLP5533A-Q1

www.ti.com

interface with the DLPC230-Q1. The mechanical output is the state of more than 1.3 million mirrors in the DMD array that can be tilted ±12°. In a projection system the mirrors are used as pixels in order to display an image.

8.2.2 Reference Design

For information about connecting together the DLP5533A-Q1 DMD, DLPC230-Q1 controller, and TPS99001-Q1, please contact the TI Application Team for additional information about the DLP5533A-Q1 evaluation module (EVM). TI has optical-mechanical reference designs available, see the TI Application team for more information.

8.2.3 Application Mission Profile Consideration

Each application is anticipated to have different mission profiles, or number of operating hours at different temperatures. To assist in evaluation the Application Report Reliability Lifetime Estimates for DLP3030-Q1 and DLP553x-Q1 DMDs in Automotive Applications may be provided. See the TI Application team for more information.



9 Power Supply Recommendations

The following power supplies are all required to operate the DMD: VDD, VDDI, VOFFSET, VBIAS, and VRESET. All VSS connections are also required. DMD power-up and power-down sequencing is strictly controlled by the TPS99001-Q1 device.

CAUTION

For reliable operation of the DMD, the following power supply sequencing requirements must be followed. Failure to adhere to the prescribed power-up and power-down procedures may affect device reliability.

VDD, VDDI, VOFFSET, VBIAS, and VRESET power supplies have to be coordinated during power-up and power-down operations. Failure to meet any of the below requirements will result in a significant reduction in the DMD's reliability and lifetime. VSS must also be connected.

9.1 Power Supply Power-Up Procedure

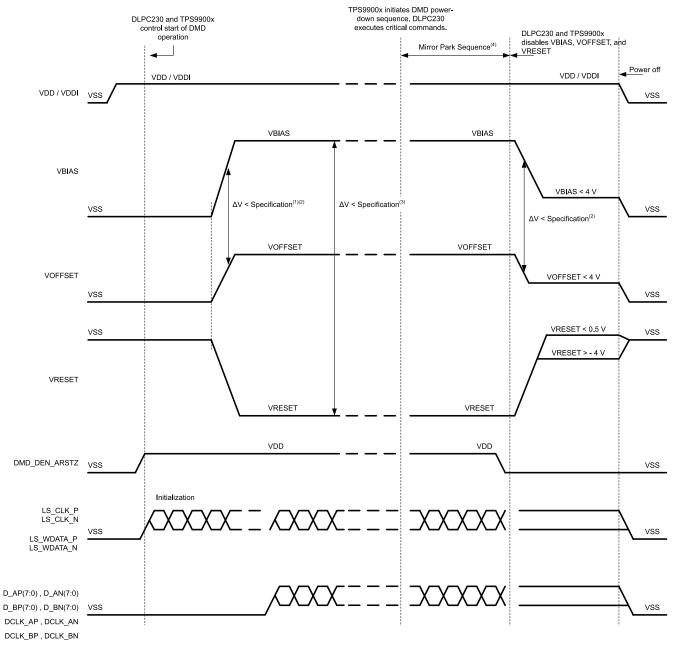
- During power-up, VDD and VDDI must always start and settle before VOFFSET, VBIAS, and VRESET voltages are applied to the DMD.
- During power-up, it is a strict requirement that the delta between VBIAS and VOFFSET must be within the specified limit shown in the *Recommended Operating Conditions*.
- During power-up, the DMD's LPSDR input pins shall not be driven high until after VDD and VDDI have settled at operating voltage.
- During power-up, there is no requirement for the relative timing of VRESET with respect to VOFFSET and VBIAS. Power supply slew rates during power-up are flexible, provided that the transient voltage levels follow the requirements listed previously and in Figure 9-1.

9.2 Power Supply Power-Down Procedure

- The power-down sequence is the reverse order of the previous power-up sequence. VDD and VDDI must be supplied until after VBIAS, VRESET, and VOFFSET are discharged to within 4 V of ground.
- During power-down, it is not mandatory to stop driving VBIAS prior to VOFFSET, but it is a strict requirement that the delta between VBIAS and VOFFSET must be within the specified limit shown in the *Recommended Operating Conditions* (Refer to Note 2 in Section 9.3).
- During power-down, the DMD's LPSDR input pins must be less than VDDI, the specified limit shown in the *Recommended Operating Conditions*.
- During power-down, there is no requirement for the relative timing of VRESET with respect to VOFFSET and VBIAS.
- Power supply slew rates during power-down are flexible, provided that the transient voltage levels follow the requirements listed previously and in Section 9.3.

Product Folder Links: DLP5533A-Q1

9.3 Power Supply Sequencing Requirements



- A. To prevent excess current, the supply voltage delta |VBIAS VOFFSET| must be less than specified in the Recommended Operating Conditions. OEMs may find that the most reliable way to ensure this is to power VOFFSET prior to VBIAS during power-up and to remove VBIAS prior to VOFFSET during power-down. Also, the TPS99001-Q1 is capable of managing the timing between VBIAS and VOFFSET.
- B. To prevent excess current, the supply voltage delta |VBIAS VRESET| must be less than specified than the limit shown in the Recommended Operating Conditions.
- C. When system power is interrupted, the TPS99001-Q1 initiates hardware power-down that disables VBIAS, VRESET and VOFFSET after the Micromirror Park Sequence.
- D. Drawing is not to scale and details are omitted for clarity.

Figure 9-1. Power Supply Sequencing Requirements (Power Up and Power Down)



10 Layout

10.1 Layout Guidelines

Please refer to the DLPC230-Q1 and TPS99001-Q1 data sheets for specific PCB layout and routing guidelines. For specific DMD PCB guidelines, use the following:

- · Match lengths for the LS WDATA and LS CLK signals.
- Minimize vias, layer changes, and turns for the HS bus signals.
- Minimum of two 220-nF decoupling capacitors close to VBIAS.
- Minimum of two 220-nF decoupling capacitors close to VRESET.
- Minimum of two 220-nF decoupling capacitors close to VOFFSET.
- Minimum of four 100-nF decoupling capacitors close to VDDI and VDD.
- · Temperature diode pins

The DMD has an internal diode (PN junction) that is intended to be used with an external TI TMP411 temperature sensing IC. PCB traces from the DMD's temperature diode pins to the TMP411 are sensitive to noise. Please see the TMP411 data sheet for specific routing recommendations.

Submit Document Feedback



11 Device and Documentation Support

11.1 Device Support

11.1.1 Device Nomenclature

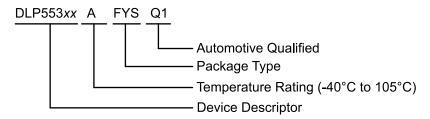


Figure 11-1. Part Number Description

11.1.2 Device Markings

The device marking includes the legible character string GHJJJJK DLP553xxAFYSQ1. GHJJJJK is the lot trace code. DLP553xxAFYSQ1 is the part number.

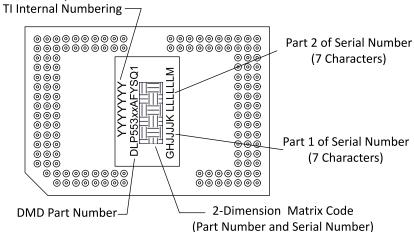


Figure 11-2. DMD Marking

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

DLP® is a registered trademark of Texas Instruments.

All trademarks are the property of their respective owners.



11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 DMD Handling

The DMD is an optical device so precautions should be taken to avoid damaging the glass window. Please see the application note DLPA019 DMD Handling for instructions on how to properly handle the DMD.

11.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: DLP5533A-Q1

www.ti.com 7-Oct-2021

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
DLP5533AAFYSQ1	ACTIVE	CPGA	FYS	149	33	RoHS & Green	Call TI	N / A for Pkg Type	-40 to 105		Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

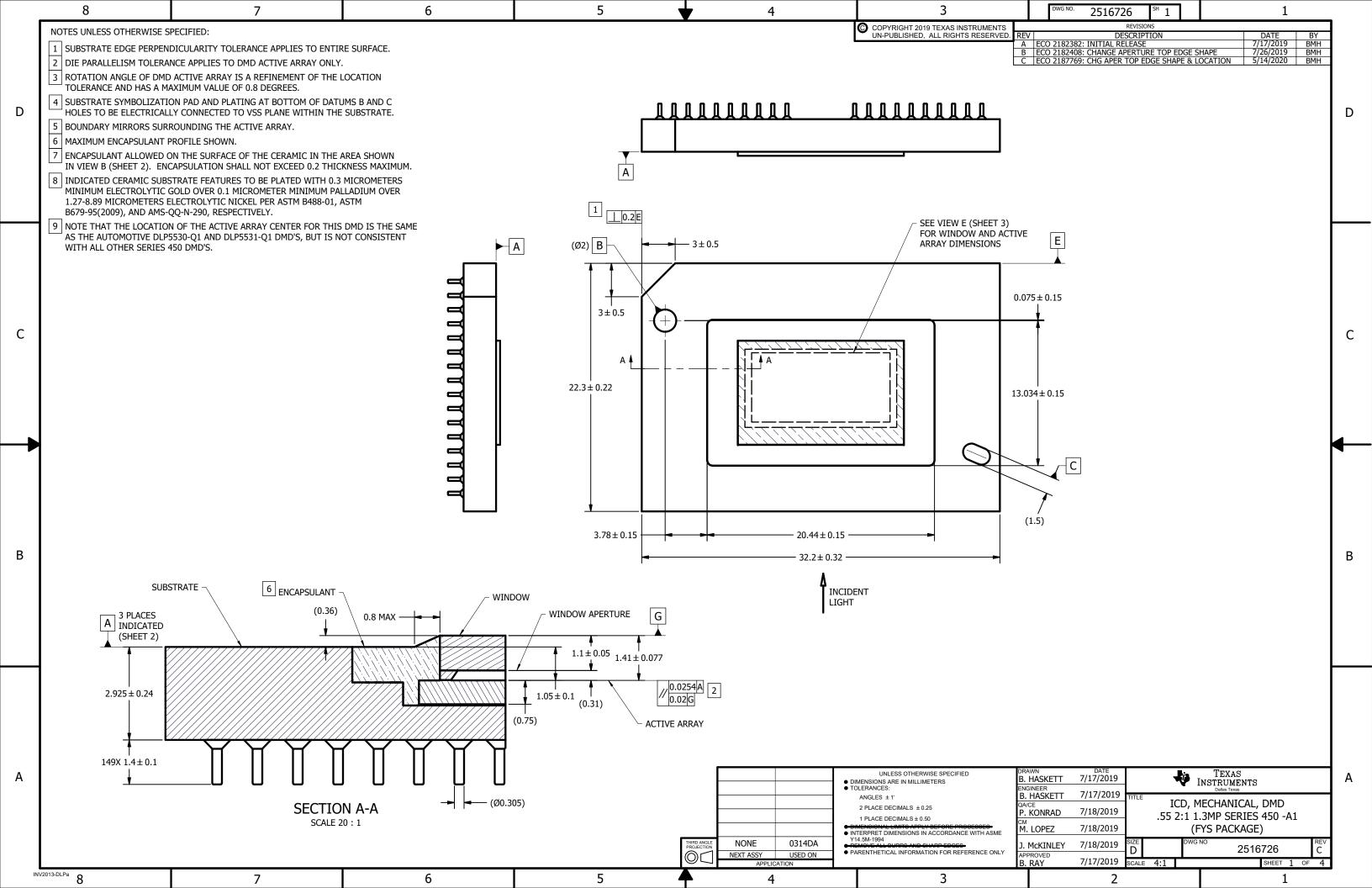
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

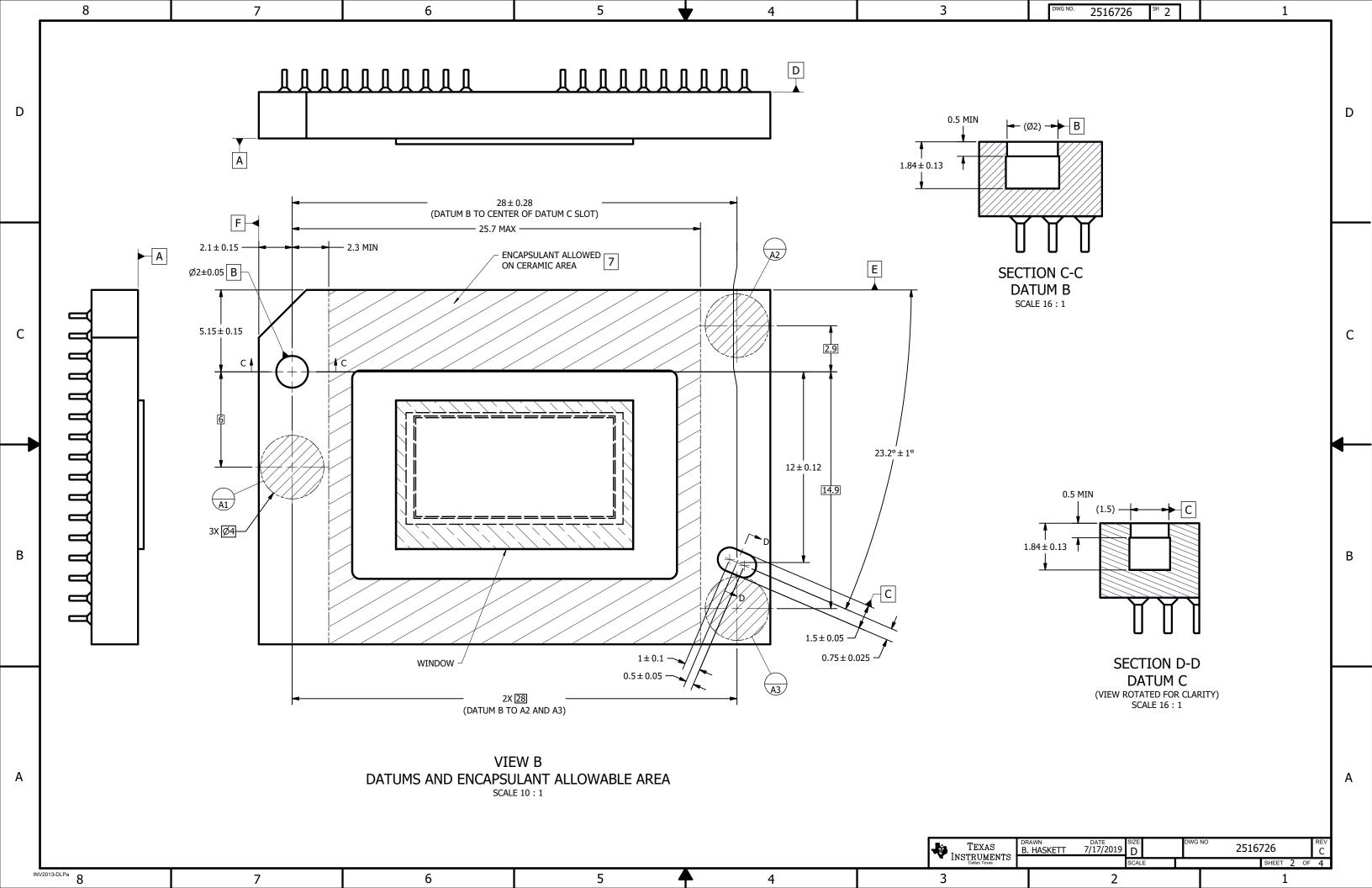
Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

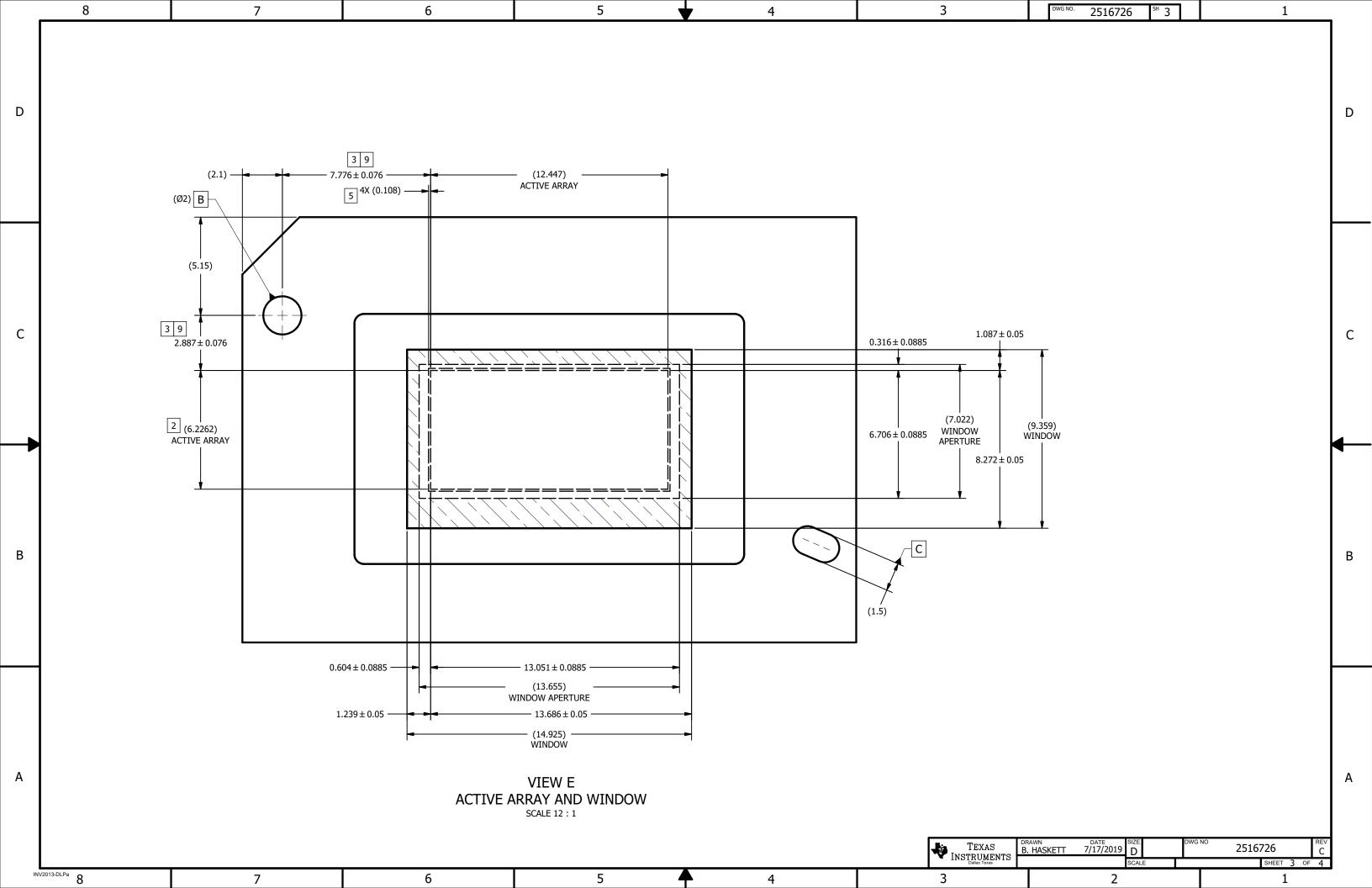
- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

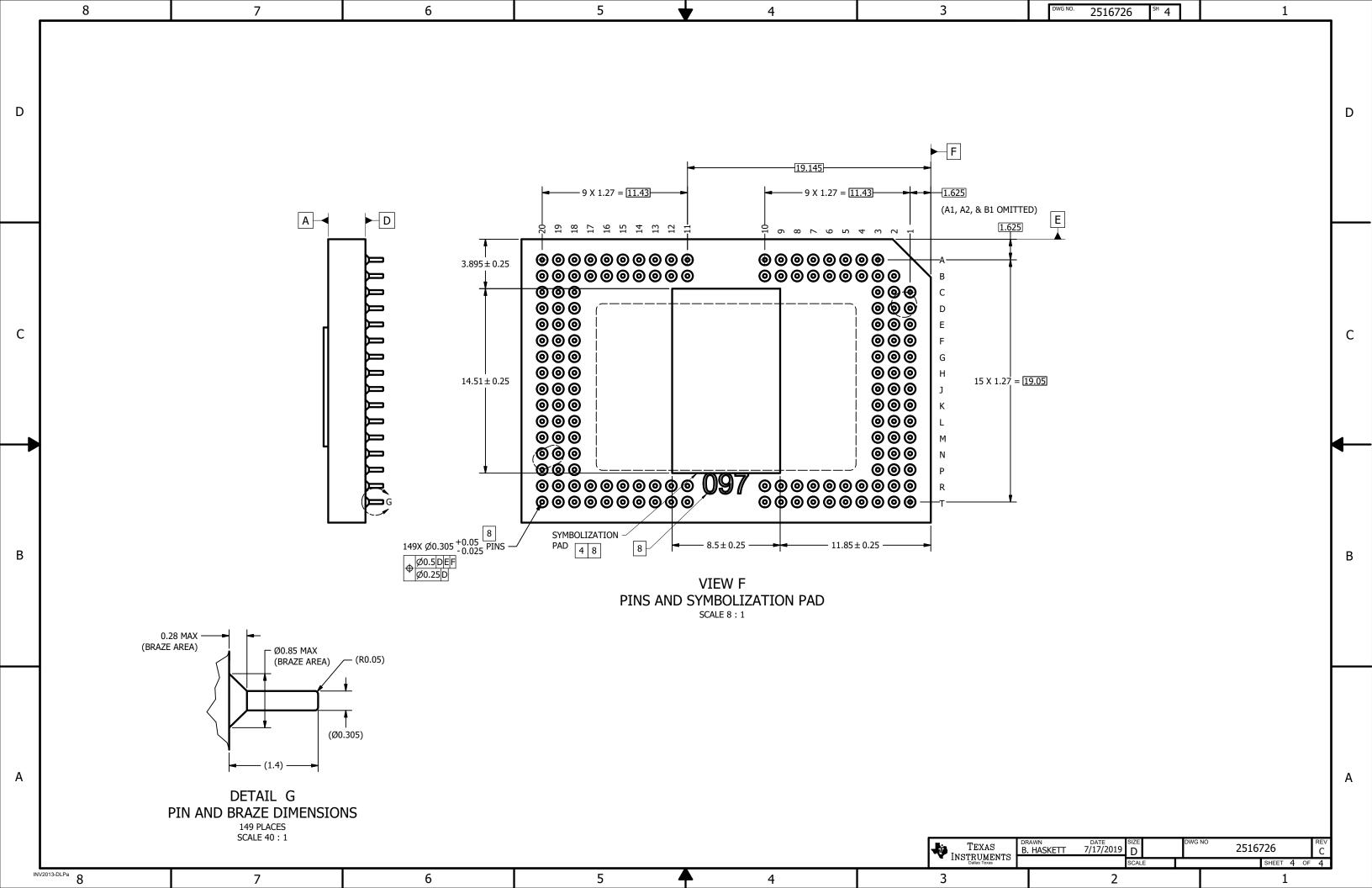
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.









IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated